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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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uClamp0508T Low Profile µClamp™ 8-Line ESD protection

PROTECTION PRODUCTS - MicroClamp™

Description

The $\mu Clamp^{TM}$ series of TVS arrays are designed to protect sensitive electronics from damage or latch-up due to ESD. It is designed to replace multilayer varistors (MLVs) in portable applications such as cell phones, notebook computers, and other portable electronics. It features large cross-sectional area junctions for conducting high transient currents. TVS diodes offer desirable characteristics for board level protection including fast response time, low operating and clamping voltage, and no device degradation.

The $\mu\text{Clamp}^{\text{TM}}0508\text{T}$ is in a 8-pin, RoHS/WEEE compliant, SLP1713P8T package. It measures 1.7 x 1.3 mm with a nominal height of only 0.4mm. The leads are spaced at a pitch of 0.4mm and are finished with lead-free NiPdAu. Each device features eight TVS diodes with an operating voltage of 5 volts and a maximum loading capacitance of only 10pF.

They may be used to meet the ESD immunity requirements of IEC 61000-4-2, Level 4 (± 15 kV air, ± 8 kV contact discharge). The combination of small size and high ESD surge capability makes them ideal for use in portable applications such as cellular phones, digital cameras, and notebook computers.

Features

- ◆ Transient protection for data lines to IEC 61000-4-2 (ESD) ±15kV (air), ±8kV (contact) IEC 61000-4-4 (EFT) 40A (tp = 5/50ns) Cable Discharge Event (CDE)
- Ultra-small package
- Protects eight data lines
- Low clamping voltage
- Working voltage: 5V
- Low capacitance (10pF)
- Solid-state silicon-avalanche technology

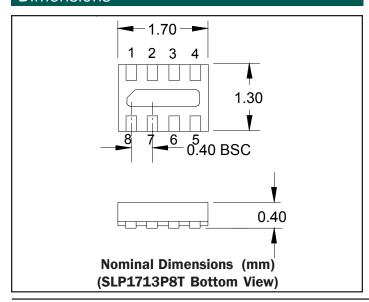
Mechanical Characteristics

- SLP1713P8T package
- ◆ RoHS/WEEE Compliant
- ◆ Nominal Dimensions: 1.7 x 1.3 x 0.4 mm
- Lead Finish: NiPdAu
- Molding compound flammability rating: UL 94V-0
- Marking: Marking code
- ◆ Packaging : Tape and Reel

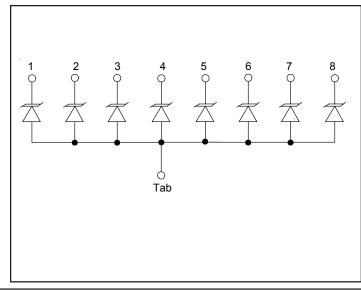
Applications

- Cellular Handsets & Accessories
- Notebooks & Handhelds
- ♠ Micro SD Ports
- ◆ MMC & HS-MMC Ports
- Portable Instrumentation
- Digital Cameras
- Peripherals

Dimensions



Schematic





Absolute Maximum Rating

Rating	Symbol	Value	Units
Peak Pulse Power (tp = 8/20μs)	P _{pk}	25	Watts
Maximum Peak Pulse Current (tp = 8/20μs)	I _{pp}	2	Amps
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	V _{ESD}	+/- 20 +/- 15	kV
Operating Temperature	T _J	-55 to +125	°C
Storage Temperature	T _{STG}	-55 to +150	°C

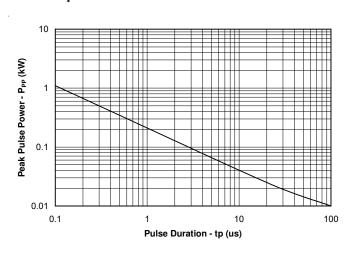
Electrical Characteristics (T=25°C)

		_				
Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units
Reverse Stand-Off Voltage	V_{RWM}				5	V
Reverse Breakdown Voltage	V _{BR}	I _t = 1mA	6			V
Reverse Leakage Current	I _R	V _{RWM} = 5V, T=25°C			0.25	μΑ
Forward Voltage	V _F	I _F = 10mA		1	1.2	V
Clamping Voltage	V _c	$I_{pp} = 2A, t_{p} = 8/20 \mu s$			12.5	V
Junction Capacitance	C _j	V _R = OV, f = 1MHz			10	pF
Junction Capacitance	C _j	V _R = 3.3V, f = 1MHz		4.5		pF

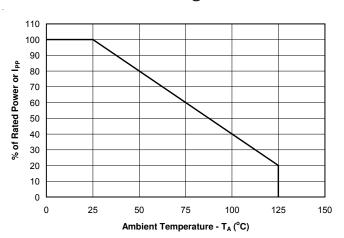


Typical Characteristics

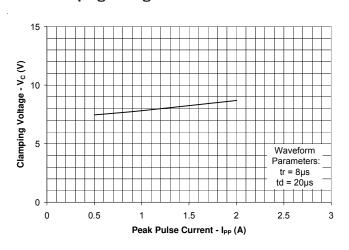
Non-Repetitive Peak Pulse Power vs. Pulse Time



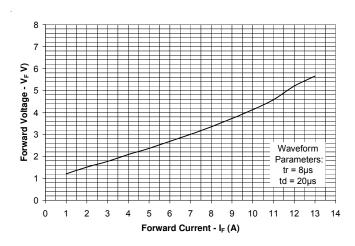
Power Derating Curve



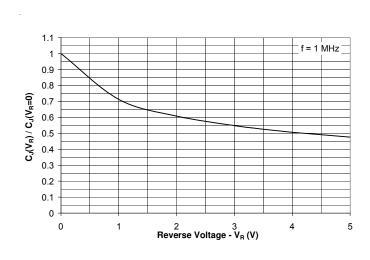
Clamping Voltage vs. Peak Pulse Current



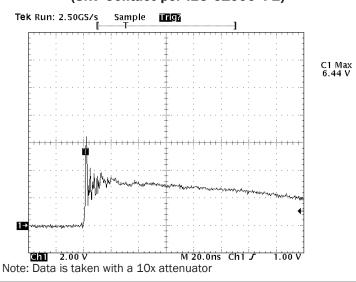
Forward Voltage vs. Forward Current



Junction Capacitance vs. Reverse Voltage



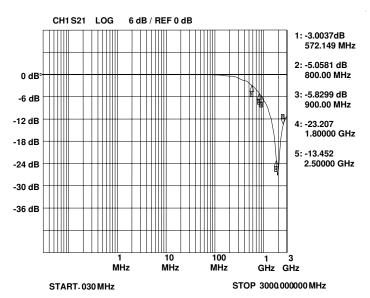
ESD Clamping (8kV Contact per IEC 61000-4-2)



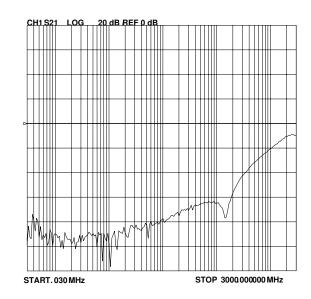


Typical Characteristics

Insertion Loss S21



Analog Crosstalk





Applications Information

Device Connection Options

This device is designed to protect eight data lines. The device is unidirectional and may be used on lines where the signal polarity is above ground.

Ground Connection Recommendation

Parasitic inductance present in the board layout will affect the filtering and ESD performance of the device. Ground loop inductance can be reduced by using multiple vias to make the connection to the ground plane. Figure 2 shows the recommended device layout. The ground pad vias have a diameter of 0.008 inches (0.20 mm) while the two external vias have a diameter of 0.010 inches (0.250mm). The internal vias are spacedapproximately evenly from the center of the pad. The designer may choose to use more vias with a smaller diameter (such as 0.005 inches or 0.125mm) since changing the diameter of the via will result in little change in inductance.

Circuit Board Layout Recommendations for Suppression of ESD.

Good circuit board layout is critical for the suppression of ESD induced transients. The following guidelines are recommended:

- Place the TVS near the input terminals or connectors to restrict transient coupling.
- Minimize the path length between the TVS and the protected line.
- Minimize all conductive loops including power and ground loops.
- The ESD transient return path to ground should be kept as short as possible.
- Never run critical signals near board edges.
- Use ground planes whenever possible.

Figure 1 - Circuit Diagram (Eight Each)

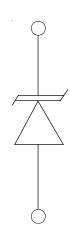
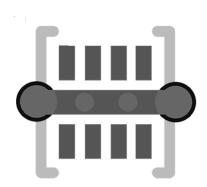
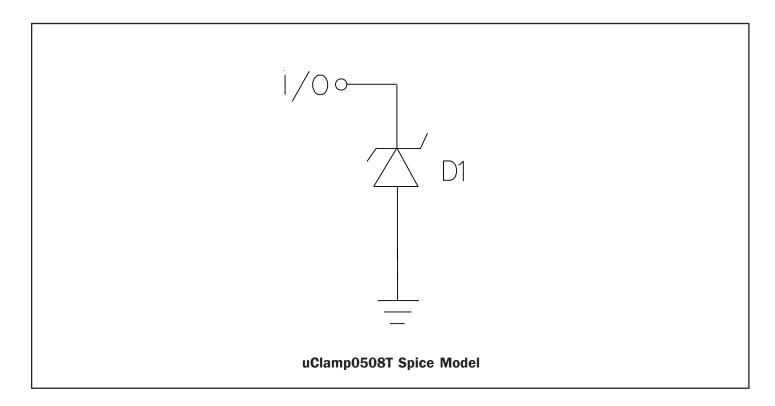


Figure 2 - Recommended Layout using Ground Vias





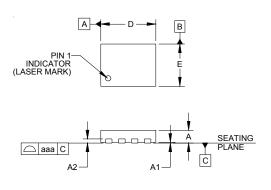
Applications Information - Spice Model



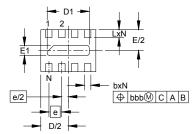
uClamp0508T Spice Parameters								
Parameter	Unit	D1 (TVS)						
IS	Amp	2.05e-15						
BV	Volt	7.0						
VJ	Volt	0.80						
RS	Ohm	0.75						
IBV	Amp	1.0E-3						
C10	Farad	9e-12						
TT	sec	2.541E-9						
М		0.25						
N		1.1						
EG	eV	1.11						



Outline Drawing - SLP1713P8T



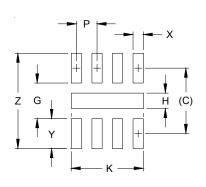
	DIMENSIONS								
DIM	11	NCHE	S	MILLIMETERS					
ווועו	MIN	NOM	MAX	MIN	NOM	MAX			
Α	.015	.016	.017	0.37	0.40	0.43			
A1	.000	.001	.002	0.00	0.02	0.05			
A2		(.005)			(0.13)				
b	.006	.008	.010	0.15	0.20	0.25			
D	.065 .067		.070	1.65	1.70	1.78			
D1	.047	.051	.055	1.20	1.30	1.40			
E	.049	.051	.054	1.25	1.30	1.38			
E1	.008	.012	.016	0.20	0.30	0.40			
е	.0	16 BS	C	0.40 BSC					
L	.008	.010	.012	0.20	0.25	0.30			
N		8		8					
aaa	.003			0.08					
bbb		.004		0.10					



NOTES:

- 1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).
- 2. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

Land Pattern - SLP1713P8T



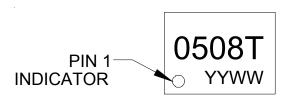
	DIMENSIONS							
DIM	INCHES	MILLIMETERS						
С	(.050)	(1.27)						
G	.027	0.69						
Н	.012	0.30						
Κ	.055	1.40						
Р	.016	0.40						
Χ	.008	0.20						
Υ	.023	0.58						
Z	.073	1.85						

NOTES:

- 1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).
- 2. THIS LAND PATTERN IS FOR REFERENCE PURPOSES ONLY. CONSULT YOUR MANUFACTURING GROUP TO ENSURE YOUR COMPANY'S MANUFACTURING GUIDELINES ARE MET.
- 3. THERMAL VIAS IN THE LAND PATTERN OF THE EXPOSED PAD SHALL BE CONNECTED TO A SYSTEM GROUND PLANE.
 FAILURE TO DO SO MAY COMPROMISE THE THERMAL AND/OR FUNCTIONAL PERFORMANCE OF THE DEVICE.



Marking Code



Ordering Information

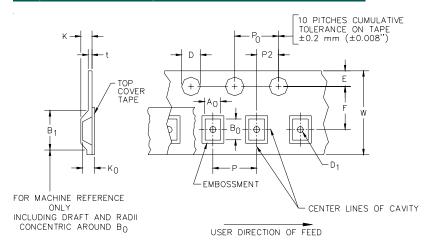
Part Number	Working	Qty per	Reel	
	Voltage	Reel	Size	
uClamp0508T.TCT	5V	3,000	7 Inch	

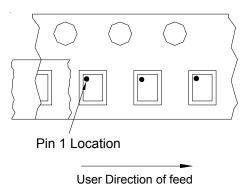
Notes:

1) This is a lead-free, RoHS/WEEE compliant product MicroClamp, uClamp and μClamp are marks of Semtech Corporation

Note: YYWW = Date Code

Tape and Reel Specification





Device Orientation in Tape

A0	ВО	ко		
1.51 +/-0.10 mm	1.91 +/-0.10 mm	0.66 +/-0.10 mm		

Tape Width	B, (Max)	D	D1	E	F	K (MAX)	Р	PO	P2	T(MAX)	W
8 mm	4.2 mm (.165)	1.5 + 0.1 mm - 0.0 mm (0.59 +.005 000)	0.8 mm ±0.05 (.031)	1.750±.10 mm (.069±.004)	3.5±0.05 mm (.138±.002)	2.4 mm (.094)	4.0±0.1 mm (.157±.00- 4)	4.0±0.1 mm (.157±.00- 4)	2.0±0.05m- m (.079±.002)	0.4 mm (.016)	8.0 mm + 0.3 mm - 0.1 mm (.312±.012)

Contact Information

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